

200V 8.8mΩ N-Ch Power MOSFET

Features

- Ultra-low ON-resistance, $R_{DS(ON)}$
- Low Gate Charge, Q_g
- 100% UIS and R_g Tested
- Pb-free Lead Plating
- Halogen-free and RoHS-compliant

Product Summary

| Parameter | Value | Unit |
|--|-------|------|
| V_{DS} | 200 | V |
| $V_{GS(th)}_{Typ}$ | 3.3 | V |
| I_D (@ $V_{GS} = 10V$) ⁽¹⁾ | 130 | A |
| $R_{DS(ON)}_{Typ}$ (@ $V_{GS} = 10V$) | 8.8 | mΩ |

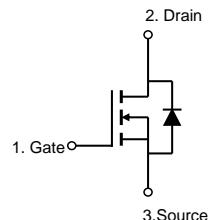
Applications

- Power Management in Computing, CE, IE 4.0, Communications
- Current Switching in DC/DC & AC/DC (SR) Sub-systems
- Load Switching, Quick/Wireless Charging, Motor Driving

TO-247-3L Top View



TO-247-3L Bottom View



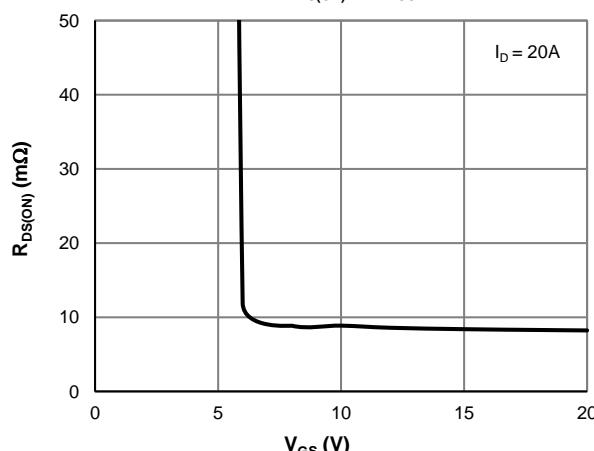
Ordering Information

| Device | Package | # of Pins | Marking | MSL | T_J (°C) | Media | Quantity (pcs) |
|--------------|-----------|-----------|---------|-----|------------|-------|----------------|
| JMSH2010BS-U | TO-247-3L | 3 | SH2010B | NA | -55 to 175 | Tube | 30 |

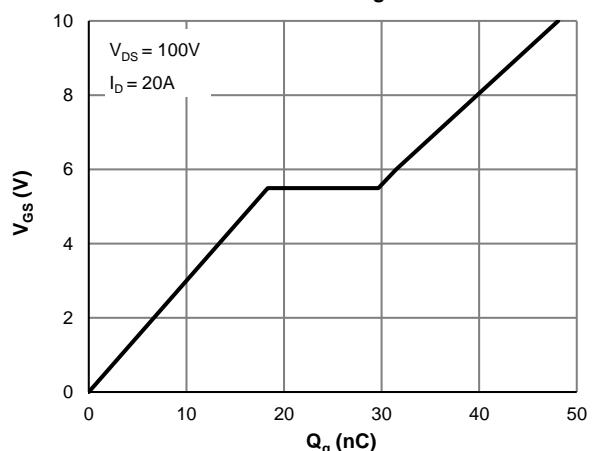
Absolute Maximum Ratings (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

| Parameter | Symbol | Value | Unit |
|---|----------------|------------|------|
| Drain-to-Source Voltage | V_{DS} | 200 | V |
| Gate-to-Source Voltage | V_{GS} | ± 20 | V |
| Continuous Drain Current ⁽¹⁾ | I_D | 130 | A |
| $T_C = 100^\circ\text{C}$ | | 92 | |
| Pulsed Drain Current ⁽²⁾ | I_{DM} | 519 | A |
| Avalanche Current ⁽³⁾ | I_{AS} | 41 | A |
| Avalanche Energy ⁽³⁾ | E_{AS} | 841 | mJ |
| Power Dissipation ⁽⁴⁾ | P_D | 500 | W |
| $T_C = 100^\circ\text{C}$ | | 250 | |
| Junction & Storage Temperature Range | T_J, T_{STG} | -55 to 175 | °C |

$R_{DS(ON)}$ vs. V_{GS}



Gate Charge



Electrical Characteristics (@ $T_J = 25^\circ\text{C}$ unless otherwise specified)

| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
|---|-----------------------------|--|------|------|------------|------------------|
| STATIC PARAMETERS | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(\text{BR})\text{DSS}}$ | $I_D = 250\mu\text{A}, V_{GS} = 0\text{V}$ | 200 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 160\text{V}, V_{GS} = 0\text{V}$ $T_J = 55^\circ\text{C}$ | | | 1.0 5.0 | μA |
| Gate-Body Leakage Current | I_{GSS} | $V_{DS} = 0\text{V}, V_{GS} = \pm 20\text{V}$ | | | ± 100 | nA |
| Gate Threshold Voltage | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | 2.5 | 3.3 | 4.5 | V |
| Static Drain-Source ON-Resistance | $R_{DS(\text{ON})}$ | $V_{GS} = 10\text{V}, I_D = 20\text{A}$ | | 8.8 | 10.6 | $\text{m}\Omega$ |
| Forward Transconductance | g_{FS} | $V_{DS} = 5\text{V}, I_D = 20\text{A}$ | | 55 | | S |
| Diode Forward Voltage | V_{SD} | $I_S = 1\text{A}, V_{GS} = 0\text{V}$ | | 0.67 | 1.0 | V |
| Diode Continuous Current | I_S | $T_C = 25^\circ\text{C}$ | | | 130 | A |
| DYNAMIC PARAMETERS⁽⁶⁾ | | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0\text{V}, V_{DS} = 100\text{V}, f = 1\text{MHz}$ | | 3318 | | pF |
| Output Capacitance | C_{oss} | | | 436 | | pF |
| Reverse Transfer Capacitance | C_{rss} | | | 41 | | pF |
| Gate Resistance | R_g | $V_{GS} = 0\text{V}, V_{DS} = 0\text{V}, f = 1\text{MHz}$ | | 3.4 | | Ω |
| SWITCHING PARAMETERS⁽⁶⁾ | | | | | | |
| Total Gate Charge (@ $V_{GS} = 10\text{V}$) | Q_g | $V_{GS} = 0 \text{ to } 10\text{V}$ $V_{DS} = 100\text{V}, I_D = 20\text{A}$ | | 48 | | nC |
| Total Gate Charge (@ $V_{GS} = 6.0\text{V}$) | Q_g | | | 32 | | nC |
| Gate Source Charge | Q_{gs} | | | 18.3 | | nC |
| Gate Drain Charge | Q_{gd} | | | 11.3 | | nC |
| Turn-On Delay Time | $t_{D(\text{on})}$ | $V_{GS} = 10\text{V}, V_{DS} = 100\text{V}$ $R_L = 5.0\Omega, R_{\text{GEN}} = 6\Omega$ | | 18.3 | | ns |
| Turn-On Rise Time | t_r | | | 27 | | ns |
| Turn-Off Delay Time | $t_{D(\text{off})}$ | | | 38 | | ns |
| Turn-Off Fall Time | t_f | | | 19.4 | | ns |
| Body Diode Reverse Recovery Time | t_{rr} | $I_F = 15\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$ | | 130 | | ns |
| Body Diode Reverse Recovery Charge | Q_{rr} | $I_F = 15\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$ | | 667 | | nC |

Thermal Performance

| Parameter | Symbol | Typ. | Max. | Unit |
|---|-----------------|------|------|--------------------|
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 50 | 60 | $^\circ\text{C/W}$ |
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 0.30 | 0.36 | $^\circ\text{C/W}$ |

Notes:

1. Computed continuous current assumes the condition of $T_{J_{\text{Max}}}$ while the actual continuous current depends on the thermal & electro-mechanical application board design.
2. This single-pulse measurement was taken under $T_{J_{\text{Max}}} = 175^\circ\text{C}$.
3. This single-pulse measurement was taken under the following condition [$L = 1\text{mH}, V_{GS} = 10\text{V}, V_{DD} = 100\text{V}$] while its value is limited by $T_{J_{\text{Max}}} = 175^\circ\text{C}$.
4. The power dissipation P_D is based on $T_{J_{\text{Max}}} = 175^\circ\text{C}$.
5. This value is guaranteed by design hence it is not included in the production test.

Typical Electrical & Thermal Characteristics

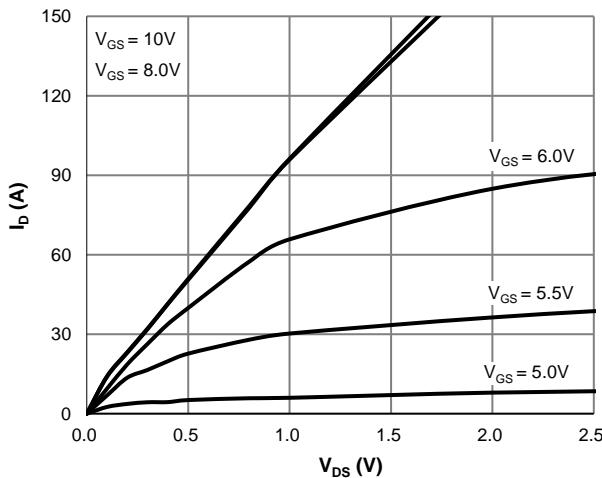


Figure 1: Saturation Characteristics

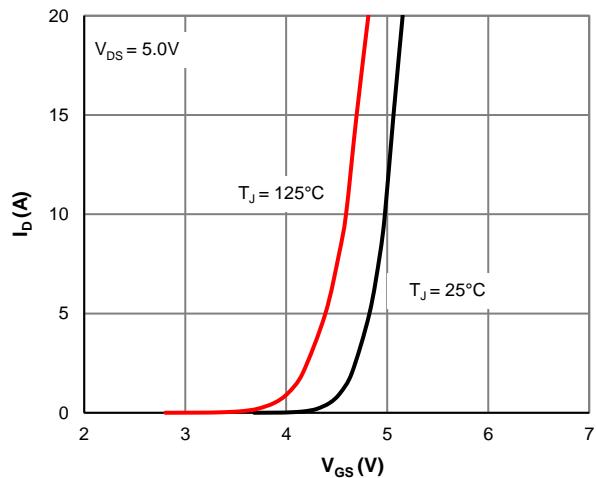


Figure 2: Transfer Characteristics

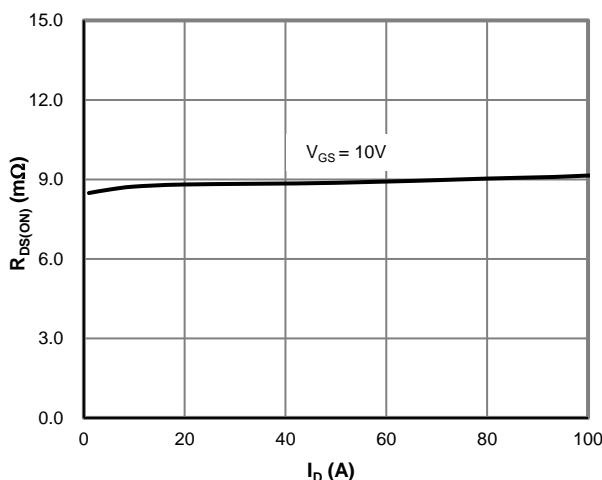


Figure 3: $R_{DS(ON)}$ vs. Drain Current

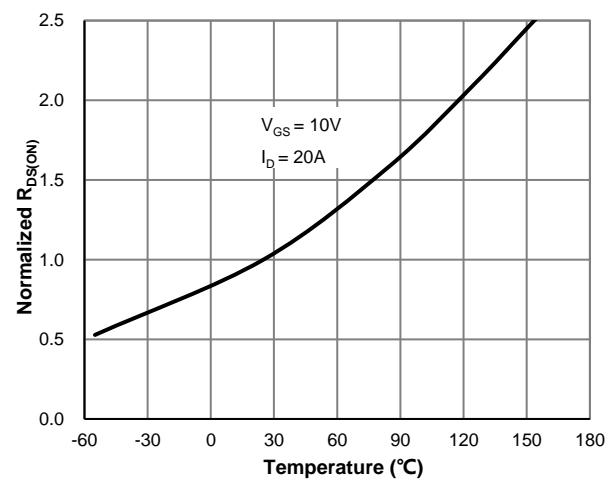


Figure 4: $R_{DS(ON)}$ vs. Junction Temperature

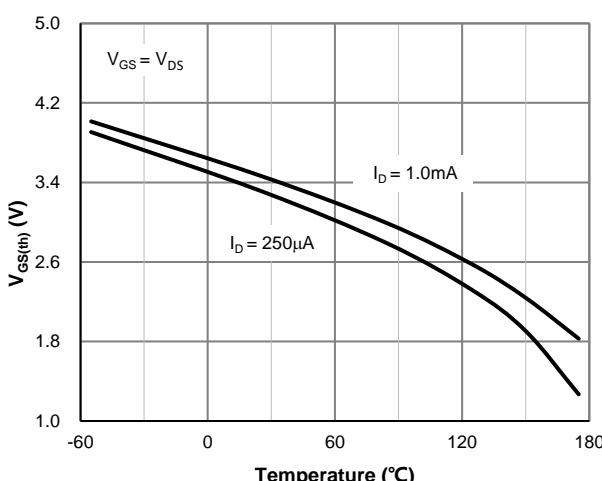


Figure 5: $V_{GS(th)}$ vs. Junction Temperature

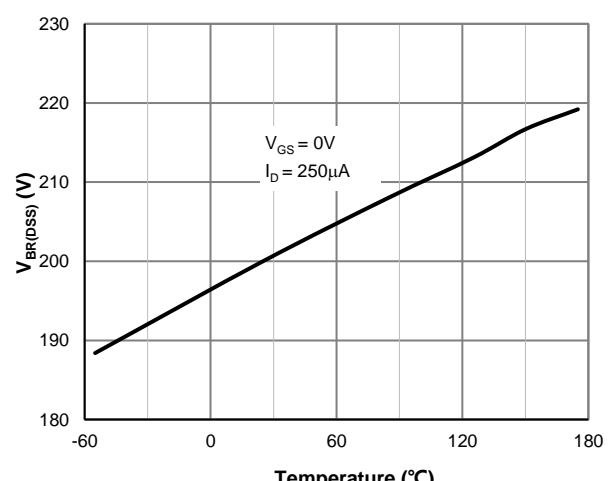


Figure 6: $V_{BR(DSS)}$ vs. Junction Temperature

Typical Electrical & Thermal Characteristics

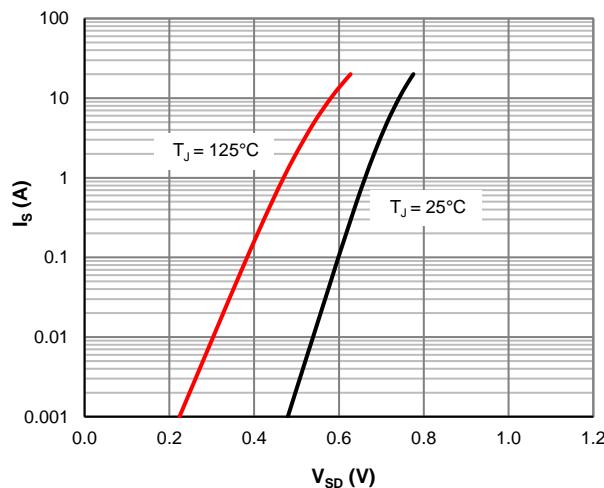


Figure 7: Body-Diode Characteristics

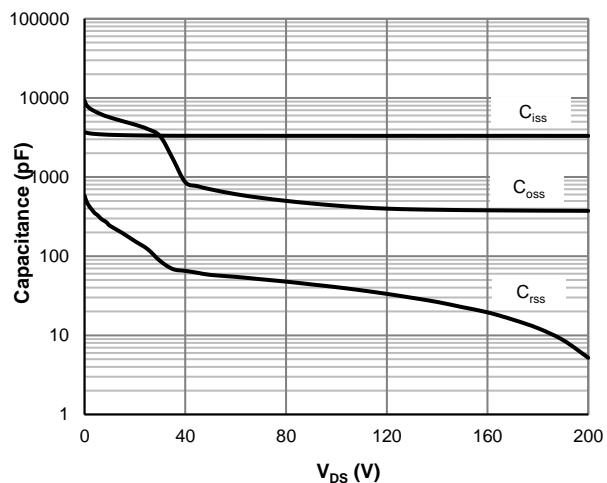


Figure 8: Capacitance Characteristics

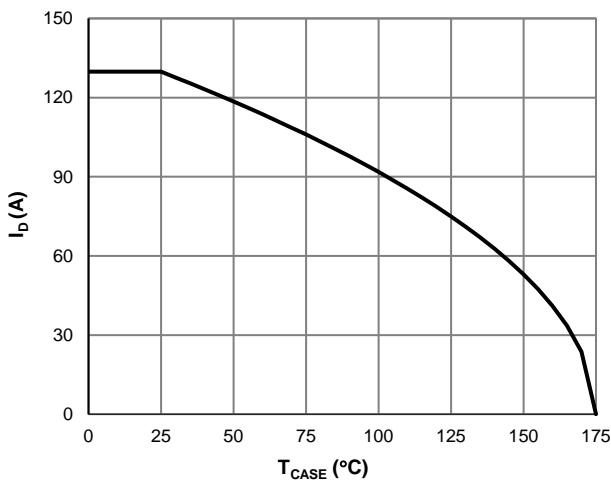


Figure 9: Current De-rating

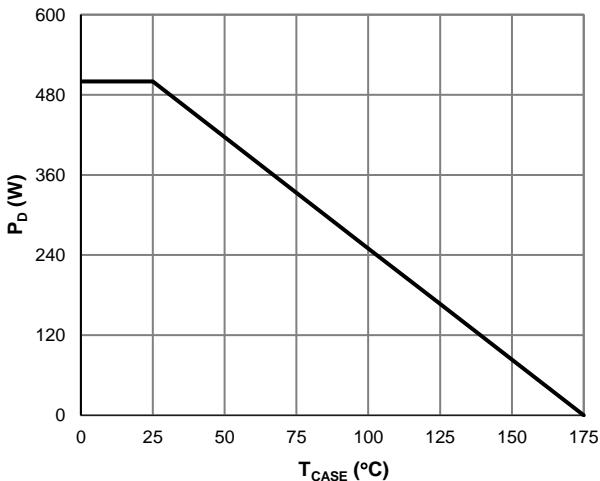


Figure 10: Power De-rating

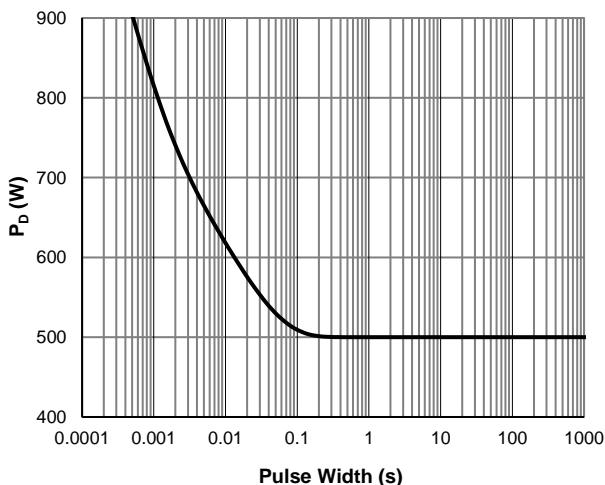


Figure 11: Single Pulse Power Rating, Junction-to-Case

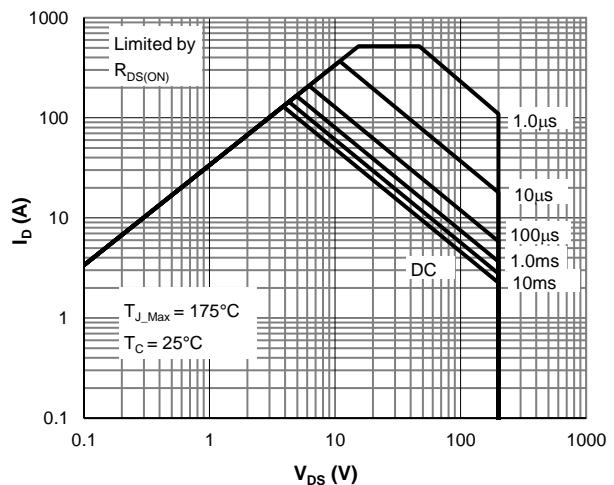


Figure 12: Maximum Safe Operating Area

Typical Electrical & Thermal Characteristics

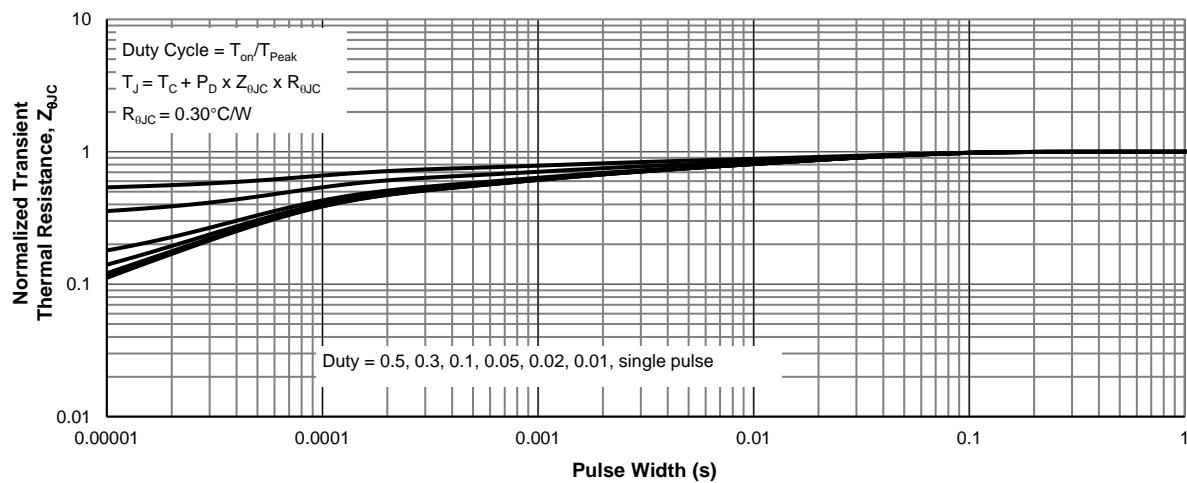
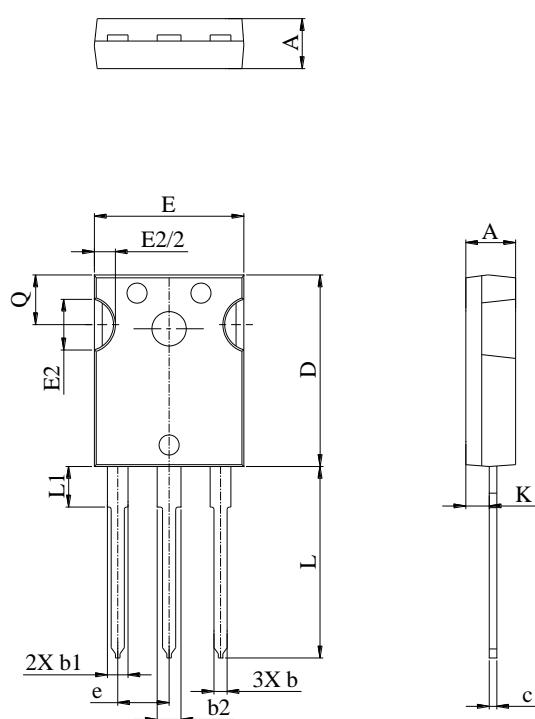


Figure 13: Normalized Maximum Transient Thermal Impedance

TO-247-3L Package Information**Package Outline**

| DIM. | MILLIMETER | | |
|------|------------|-------|-------|
| | MIN. | NOM. | MAX. |
| A | 4.80 | 5.02 | 5.21 |
| b | 1.00 | 1.20 | 1.40 |
| b1 | 1.90 | 2.00 | 2.39 |
| b2 | 2.87 | 3.00 | 3.22 |
| c | 0.41 | 0.60 | 0.79 |
| D | 20.80 | 21.00 | 21.20 |
| E | 15.50 | 15.94 | 16.13 |
| E2 | 4.32 | | 5.49 |
| L | 19.70 | 20.07 | 20.32 |
| L1 | 4.00 | | 4.40 |
| K | 2.20 | | 2.50 |
| e | 5.44 BSC | | |